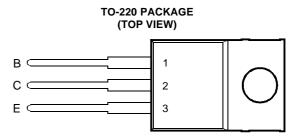
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- Rugged Triple-Diffused Planar Construction
- 4 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- 1000 Volt Blocking Capability



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | SYMBOL | VALUE | UNIT | | |
|---|------------------|------------------|------|---|--|
| Collector base voltage $(I_{-}, 0)$ | TIPL791 | | 850 | V | |
| Collector-base voltage ($I_E = 0$) | TIPL791A | V _{CBO} | 1000 | v | |
| Collector-emitter voltage ($V_{RE} = 0$) | TIPL791 | M | 850 | V | |
| $Collector-entitler voltage (v_{BE} = 0)$ | TIPL791A | V _{CES} | 1000 | v | |
| Collector omitter veltage $(I_{-} = 0)$ | TIPL791 | M | 400 | V | |
| Collector-emitter voltage $(I_B = 0)$ | TIPL791A | V _{CEO} | 450 | v | |
| Emitter-base voltage | V _{EBO} | 10 | V | | |
| Continuous collector current | | | 4 | A | |
| Peak collector current (see Note 1) | | | 8 | A | |
| Continuous device dissipation at (or below) 25°C case temperature | | | 75 | W | |
| Operating junction temperature range | Тj | -65 to +150 | °C | | |
| Storage temperature range | T _{stg} | -65 to +150 | °C | | |

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%.$



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electrical characteristics at 25°C case temperature (unless otherwise noted)

| l | PARAMETER | | | TEST C | ONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------------|---|---|------------------------------|---|--|--|------------|-----|--------------------------|------|
| V _{CEO(sus)} | Collector-emitter sustaining voltage | I _C = 100 | mA | L = 25 mH | (see Note 2) | TIPL791 TIPL791A | 400 450 | | | V |
| I _{CES} | Collector-emitter cut-off current | $V_{CE} = 8$ $V_{CE} = 10$ $V_{CE} = 8$ $V_{CE} = 10$ | 00 V 50 V | $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ | T _C = 100°C T _C = 100°C | TIPL791 TIPL791A TIPL791 TIPL791A | | | 5 5 200 200 | μA |
| I _{CEO} | Collector cut-off current | $V_{CE} = 4$ $V_{CE} = 4$ | | $I_B = 0$ $I_B = 0$ | | TIPL791 TIPL791A | | | 5 5 | μA |
| I _{EBO} | Emitter cut-off current | V _{EB} = | 10 V | I _C = 0 | | | | | 1 | mA |
| h _{FE} | Forward current transfer ratio | V _{CE} = | 5 V | I _C = 0.5 A | (see Notes 3 ar | nd 4) | 20 | | 60 | |
| V _{CE(sat)} | Collector-emitter saturation voltage | I _B = (| 0.2 A 0.5 A 1 A 1 A | $I_{C} = 1 A$ $I_{C} = 2.5 A$ $I_{C} = 4 A$ $I_{C} = 4 A$ | (see Notes 3 ar T _C = 100°C | nd 4) | | | 0.5 1.0 2.5 5.0 | V |
| V _{BE(sat)} | Base-emitter saturation voltage | I _B = (| 0.2 A 0.5 A 1 A 1 A | $I_{C} = 1 A$ $I_{C} = 2.5 A$ $I_{C} = 4 A$ $I_{C} = 4 A$ | (see Notes 3 ar T _C = 100°C | nd 4) | | | 1.0 1.2 1.4 1.3 | V |
| ft | Current gain bandwidth product | V _{CE} = | 10 V | I _C = 0.5 A | f = 1 MHz | | | 12 | | MHz |
| C _{ob} | Output capacitance | V _{CB} = | 20 V | $I_E = 0$ | f = 0.1 MHz | | | 110 | | pF |

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques, t_p = 300 $\mu s,$ duty cycle \leq 2%.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

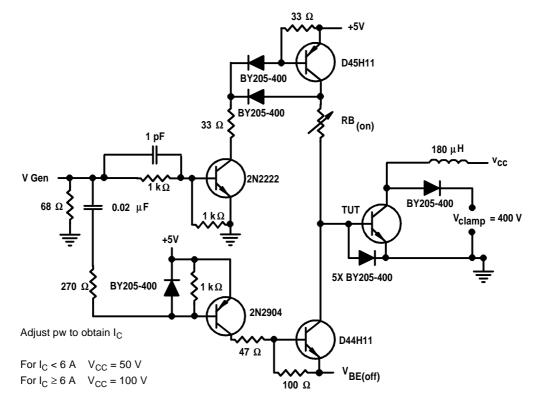
| PARAMETER | | MIN | TYP | MAX | UNIT |
|----------------|-------------------------------------|-----|-----|------|------|
| R_{\thetaJC} | Junction to case thermal resistance | | | 1.66 | °C/W |

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

| | PARAMETER | | TEST CONDITION | NS [†] | MIN | TYP | MAX | UNIT |
|-----------------|----------------------|---------------------------------------|---|-----------------------|-----|-----|-----|------|
| t _{sv} | Voltage storage time | | | | | | 2 | μs |
| t _{rv} | Voltage rise time | $I_{C} = 4 A$ $V_{BE(off)} = -5 V$ | I _{B(on)} = 0.8A | (see Figures 1 and 2) | | | 200 | ns |
| t _{fi} | Current fall time | | | | | | 100 | ns |
| t _{ti} | Current tail time | | | | | | 50 | ns |
| t _{xo} | Cross over time | | | | | | 200 | ns |
| t _{sv} | Voltage storage time | $I_{C} = 4 A$ $V_{BE(off)} = -5 V$ | I _{B(on)} = 0.8A T _C = 100°C | (see Figures 1 and 2) | | | 2.5 | μs |
| t _{rv} | Voltage rise time | | | | | | 400 | ns |
| t _{fi} | Current fall time | | | | | | 200 | ns |
| t _{ti} | Current tail time | | | | | | 50 | ns |
| t _{xo} | Cross over time | | | | | | 600 | ns |

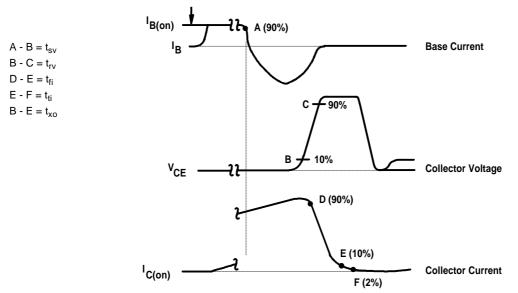
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

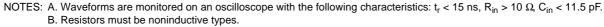
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PARAMETER MEASUREMENT INFORMATION



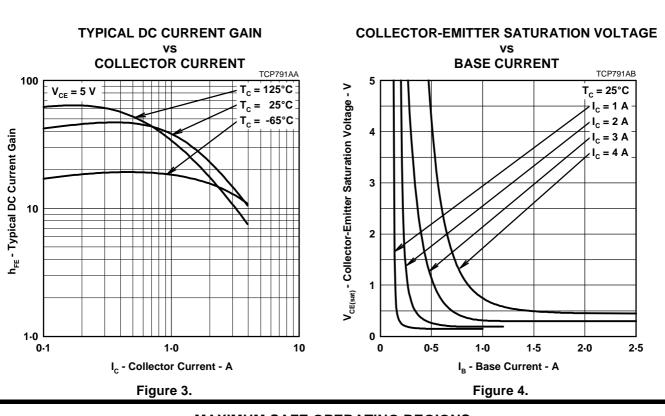






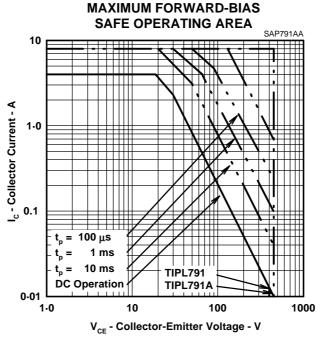


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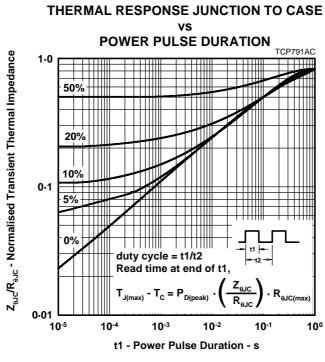
TYPICAL CHARACTERISTICS







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THERMAL INFORMATION

Figure 6.



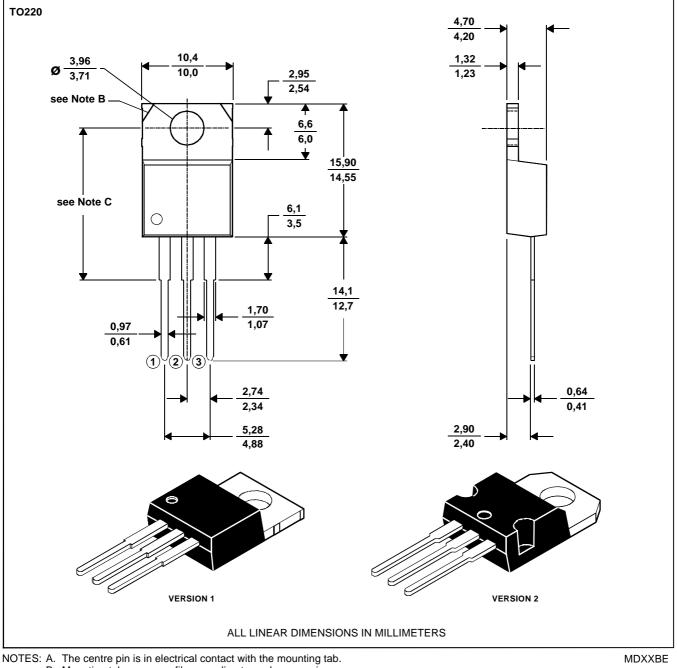
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

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